

### **General Description**

The CCA1224 is a bus interface IC with driver and receiver function. The bus driver provides two or combined inputs and a differential current bus output. The receiver uses the driver outputs as input and delivers the signal to an open collector output. This device is functional and pin compatible to the obsolete part no. HA12240.

Typical applications are automotive audio equipment controllers.

#### 1.1 FEATURES

- Two or combined data inputs (3.3 V and 5.0 V)
- · Hysteresis input comparator
- Current drive output typ. 3.8
- Hysteresis comparator for receiver
- Wide receiver commonmode input range of 0 to 5V typ.
- Open collector receiver output
- Operating VCC 5 V ±0.5 V
- Standby function (IVCC < 1 μA)</li>
- ESD protection 2 kV
- on all IO pins
- SOP8 package
- Automotive qualified (AECQ100)

#### 1.2 SCHEMATIC

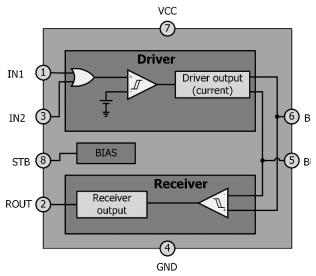


Figure 1: Block Diagram



### 2 Pinout

### 2.1 PACKAGE

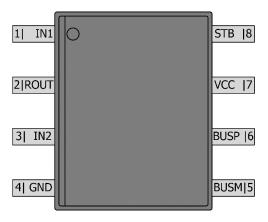


Figure 2: Package SOP8 (3.9x4.9mm)

### 2.2 PIN DESCRIPTIONS

**Table 1: Pin Descriptions** 

Symbol	Pin no.	Type	Description	Schematic
IN1	1	IN	Data input 1	①
ROUT	2	OUT	Receiver output (open collector)	20 
IN2	3	IN	Data input 2	3-20%
GND	4	PWR	Ground	*
BUSM	5	IN/OUT	Minus bus driver output, receiver input	6
BUSP	6	IN/OUT	Plus bus driver output, receiver input	(S)
VCC	7	PWR	Voltage supply	
STB	8	IN	Stand by input: H => operating mode; L => standby mode	(8) 100k



## **3 Absolute Maximum Ratings**

**Table 2: Absolute Maximum Ratings** 

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Supply Voltage	VCC	static	-0.7		36	V
Power dissipation	P <sub>TOT_QFN</sub>	Multilayer PCB, Exp. Pad soldered,			2	W
QFN48	48	$\theta_{AMB} = 60^{\circ}C$				
Power dissipation	P <sub>TOT_QFN</sub>	Multilayer PCB, Exp. Pad soldered,			1.5	W
QFN24	24	$\vartheta_{\text{AMB}} = 60^{\circ}\text{C}$				
Junction	arthetaJUNC				150	°C
Temperature						
ESD-sensitivity	V <sub>ESD</sub>	Human Body Model EIA/JESD22-	2			kV
		A114-B				
Storage	arthetaSTORAGE		-55		155	°C
Temperature						
Soldering	$artheta_{ extsf{SOLDER}}$	12 s max			260	°C
Temperature						
FIT Rate					50	FIT

Functional operation is only guaranteed within operating conditions listed under "Electrical Characteristics". Exposure to absolute maximum rating conditions for extended periods of time may affect device reliability. Exposure to conditions beyond those ratings may cause permanent damage to the device.

### **4 Electrical Characteristics**

Electrical characteristics are valid for the whole specified temperature range and supply voltage range, if not otherwise noted.

#### 4.1 GENERAL PARAMETERS

**Table 3: General Parameters** 

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Supply Voltage	VCC		4.5	5	5.5	V
Supply Current	I <sub>VCC</sub>		0.8		8.5	mA
Operating Temperature	<b>Э</b> АМВ		-40		105	°C
Thermal Resistance Ambient	∂JA_SOPN-	Junction to Ambient		100		K/W
	8					



### 4.2 DRIVER

**Table 4: Driver** 

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
High-level input voltage IN1	V <sub>IHS1</sub>	V1 = 0 V -> 5 V; V3 = 0 V; V6 - V5 = 110 mV ↑	2.1			V
Low-level input voltage IN1	V <sub>ILS1</sub>	V1 = 5 V -> 0 V; V3 = 0 V; V6 - V5 = 30 mV ↓			1.65	V
High-level input current IN1	I <sub>IHS1</sub>	V1 = 5 V	-1	0	1	μA
Low-level input current IN1	I <sub>ILS1</sub>	V1 = 0 V	-1	0.1	1	μA
High-level input voltage IN2	V <sub>IHS2</sub>	V3 = 0 V -> 5 V; V1 = 0 V; V6 - V5 = 110 mV ↑	2.1			V
Low-level input voltage IN2	V <sub>ILS2</sub>	V3 = 5 V -> 0 V; V1 = 0 V; V6 - V5 = 30 mV ↓			1.65	V
High-level input current IN2	I <sub>ILS2</sub>	V3 = 5 V	-1	0	1	μA
Low-level input current IN2	I <sub>ILS2</sub>	V3 = 0 V	-1	0.1	1	μA
High-level output voltage BUSP	V <sub>OHDP</sub>	V1 or V3 > 2.1 V	1.8	2.5	3.2	V
Low-level output voltage BUSM	V <sub>OHDM</sub>	V1 or V3 > 2.1 V	1.8	2.5	3.2	V
High-level output current (BUSP out; BUSM in)	Іон	V1 or V3 > 2.1 V	3.1	3.8	4.5	mA
Low-level output voltage BUSP, BUSM	Vold	V1 and V3 < 1.65 V	2.3	2.5	2.7	V
Driver output resistance	Ro	V1 or V3 > 2.1 V Fehler! Verweisquelle konnte nicht gefunden werden 3; measure $I6_1$ at V6 = V <sub>OLD</sub> + 0.3 V then measure $I6_2$ at V6 = V <sub>OLD</sub> - 0.3 V; R <sub>O</sub> = 0.6 V / $(I6_1 - I6_2)$	5	10	15	kΩ
Driver delay time low -> high	T <sub>DDR</sub>	V1 = 4.5 V ↑; V6 – V5 = 110 mV ↑;		80	150	ns
Driver delay time high -> low	T <sub>DDF</sub>	V1 = 0.5 V ↓; V6 – V5 = 30 mV ↓;		40	70	ns

### 4.3 RECEIVER

Table 5: Receiver

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
High-level input voltage at low common-mode BUSP-BUSM	V <sub>IH1</sub>	V6 = 0 V -> 5 V; V5 = 0 V; V1 = 0 V; V3 = 0 V; V2 = 4 V ↑; V <sub>IH1</sub> = V6 - V5	45	80	110	mV
High-level input voltage at high common-mode BUSP-BUSM	V <sub>IH2</sub>	V6 = 0 V -> 5 V; V5 = 4.5 V; V1 = 0 V; V3 = 0 V; V2 = 4 V ↑; V <sub>IH2</sub> = V6 - V5	45	80	110	mV
Low-level input voltage at low common-mode BUSP-BUSM	V <sub>IL1</sub>	V6 = 5 V -> 0 V; V5 = 0 V; V1 = 0 V; V3 = 0 V; V2 = 1 V ↓; V <sub>IL1</sub> = V6 - V5	30	50	95	mV
High-level input voltage at high common-mode BUSP-BUSM	V <sub>IL2</sub>	V6 = 5 V -> 0 V; V5 = 4.5 V; V1 = 0 V;	30	50	95	mV



Parameter	Symbol	Conditions	Min	Тур	Max	Unit
		$V3 = 0 V$ ; $V2 = 1 V \downarrow$ ; $V_{1L2} = V6 - V5$				
Input hysteresis voltage at low common-mode BUSP-BUSM	VIHYS1	V <sub>IHYS1</sub> = V <sub>IH1</sub> - V <sub>IL1</sub>	15	30	45	mV
Input hysteresis voltage at high common-mode BUSP-BUSM	V <sub>IHYS2</sub>	V <sub>IHYS2</sub> = V <sub>IH2</sub> - V <sub>IL2</sub>	15	30	45	mV
High-level common-mode input voltage BUSM	Vнсом	$V5 = 0 V \rightarrow 5 V$ ; $V1 = 0 V$ ; $V3 = 0 V$ ; $V_{HCOM} = V5 $ when $V2 = 4 V \downarrow$ ; $V6 - V5 = 110 $ mV	4.5			V
Low-level common-mode input voltage BUSM	V <sub>LCOM</sub>	V5 = 0 V -> 5 V; V1 = 0 V; V3 = 0 V; V <sub>HCOM</sub> = V5 when V4 = 1 V 1; V6 - V5 = 30 mV	5			V
Receiver input resistance	Rı	V1 and V3 < 1.65 V Fehler!  Verweisquelle konnte nicht gefunden werden 3; measure I63 at V6 = V <sub>OLD</sub> + 0.3 V then measure I64 at V6 = V <sub>OLD</sub> - 0.3 V; R <sub>I</sub> = 0.6 V / (I63 - I64)	25	35	45	kΩ
High-level receiver output leakage current ROUT	I <sub>ROH</sub>	V1 = 5 V; V3 = 0 V; V2 = 5 V	-1	0	1	μΑ
Standby 1 receiver output leakage current ROUT	I <sub>ROS1</sub>	V1 = 0 V; V3 = 0 V; V8 = 0 V; VCC = 0 V; V2 = 5 V	-1	0	1	μΑ
Standby 2 receiver output leakage current ROUT	I <sub>ROS2</sub>	V1 = 0 V; V3 = 0 V; V8 = 0 V; V2 = 5 V	-1	0	1	μA
Low-level 1 receiver output voltage ROUT	V <sub>ROL1</sub>	V1 = 0 V; V3 = 0 V; I2 = 1.5 mA			0.6	V
Low-level 2 receiver output voltage ROUT	V <sub>ROL2</sub>	V1 = 0 V; V3 = 0 V; I2 = 200 μA			0.3	V
Receiver delay time low -> high	T <sub>RDR</sub>	V6 – V5 = 110 mV ↑; V2 = 4.5 V ↑		600	700	ns
Receiver delay time high -> low	T <sub>RDF</sub>	V6 – V5 = 30 mV ↓; V2 = 0.5 V ↓		110	150	ns

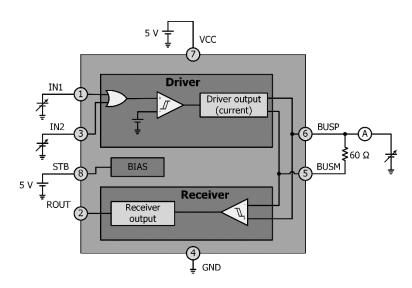
### 4.4 BIAS AND VCC

Table 6: BIAS and VCC

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Quiescent current high Vcc	Іссн	V1 or V3 > 2.1 V	3		8.5	mA
Quiescent current low V <sub>CC</sub>	Iccl	V1 and V3 < 1.65 V	8.0		1.8	mA
Standby driver output leakage current BUSP	I <sub>DOS</sub>	V8 = 0 V; V1 or V3 > 2.1 V; V6 = 5 V	-1		1	μA
Standby supply leakage current V <sub>CC</sub>	Ivccs	V8 = 0 V; V1 or V3 > 2.1 V;	-1		1	μA
Standby high-level input voltage STB	Vsтвн	V8 = 0 V -> 5 V; V1 = 0 V; V3 = 0 V; V <sub>STBH</sub> = V8 when V5, V6 = 2.3 V ↑	0.9		2	V
Standby low-level input voltage STB	V <sub>STBL</sub>	V8 = 5 V -> 0 V; V1 = 5 V; V3 = 0 V; V <sub>STBH</sub> = V8 when I <sub>VCC</sub> = 1 µA ↓	0.9		2	٧



Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Standby high-level input current STB	Іѕтвн	V8 = 5 V; V1 = 5 V; V3 = 0 V;		50	100	μA
Standby low-level input current STB	Istbl	V8 = 0 V; V1 = 5 V; V3 = 0 V;	-1	0	1	μA



**Figure 3: Measurement Circuits** 

## **5 Functional Description**

#### 5.1 DRIVER

The "Driver block" has two inputs and a differential current output. The inputs IN1 (Pin 1) and IN2 (Pin 3) are "or"-connected and their switching level and hysteresis are 3.3V and 5V compatible. The output BUSP (Pin 6) delivers a source current and BUSM (Pin 5) delivers a sink current of the same amount, so that with an external 60 Ohm Resistor between BUSP and BUSM the differential voltage is 230 mV (high) and 0 mV (low). The common-mode voltage is about 2.5 V, but the output can withstand external voltage up to VCC + 0.3V.



#### 5.2 RECEIVER

The "Receiver block" has a differential voltage input and an open collector output. It share the Pins BUSP (Pin 6) and BUSM (Pin 5) with the driver block, but for the receiver block they are the differential voltage input. They have a large common-mode operating voltage from 0 V to 4.5 V and can withstand external voltage up to VCC + 0.3V. The receiver output ROUT is open collector, so that the supply voltage for the external resistor at this Pin determines the following logic level.

#### **5.3 BIAS**

The "Bias block" delivers an internal reference voltage (2.5 V), several reference currents and the chance with the signal of Pin STB (Pin 8) to activate or deactivate the supply for all function blocks, so that in the standby mode (V(STB) < 0.9 V) the power supply current falls to less than  $1\mu$ A.

### **6 Application notes**

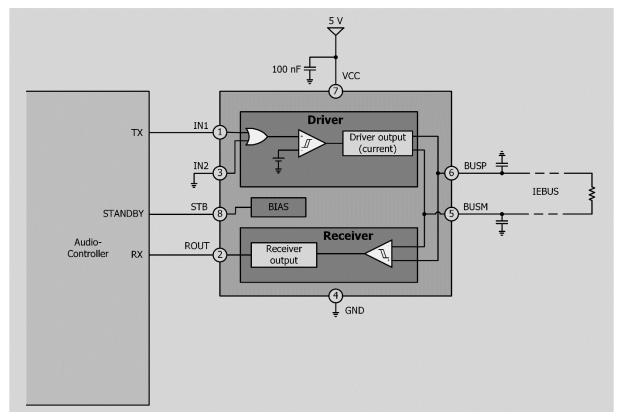
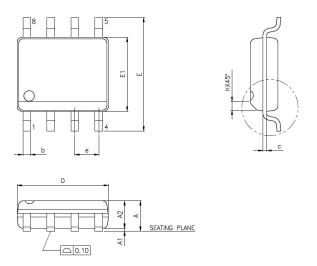


Figure 4: Application



# 7 Package Outline

### 7.1 SOP8 Package



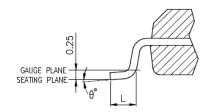


Figure 5: SOP8 Package

Symbol	Α	A1	A2	b	С	D	Е	E1	е	L	h	Θ°
Min		0.10	1.25	0.31	0.10	4.90	6.00	3.90	1.27	0.40	0.25	5.15
Max	1.75	0.25		0.51	0.25	BSC.	BSC.	BSC	BSC.	1.27	0.50	5.25

NOTES:

1.JEDEC OUTLINE: MS-012 AA REV.F (STANDARD)
MS-012 BA REV.F (THERMAL)
2.DIMENSIONS "D" DOES NOT INCLUDE MOLD FLASH,
PROTRUSIONS OR GATE BURRS.MOLD FLASH, PROTRUSIONS
AND GATE BURRS SHALL NOT EXCEED 0.15mm.

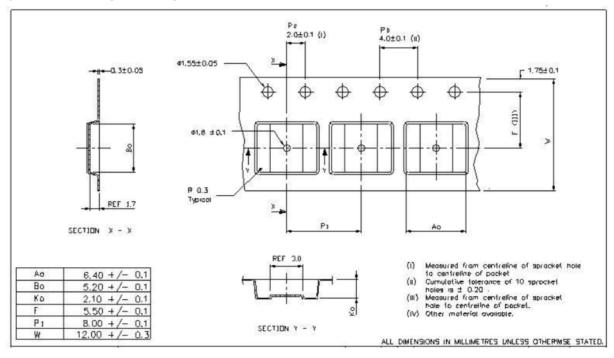
PER SIDE.

3.DIMENSIONS "E1" DOES NOT INCLUDE INTER-LEAD FLASH, OR PROTRUSIONS. INTER-LEAD FLASH AND PROTRUSIONS SHALL NOT EXCEED 0.25mm PER SIDE.



# **8 Tape and Reel Information**

### **8.1 TAPE INFORMATION**



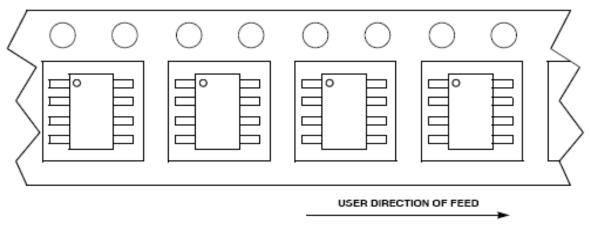
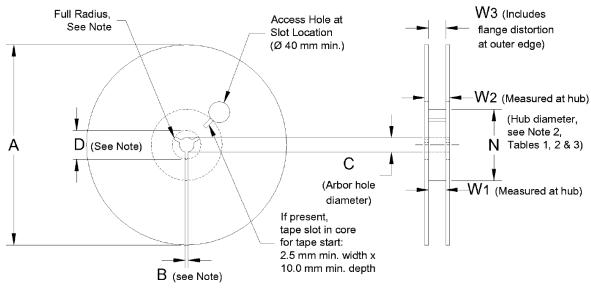


Figure 6: Tape Information



#### 8.2 Reel Information



Note: Drive spokes optional; if used, dimensions B and D shall apply.

Figure 7: Reel Information

Symbol	Α	В	С	D	$\mathbf{W}_1$
Minimal	-	1.5	12.8	20.2	13.25
Typical	-	-	13.0	ı	-
Maximum	330	-	13.5	-	13.75

# **9 Ordering Information**

**Table 7: Ordering Information** 

Part	Order No.	Package	Delivery	Quantity
CCA1224	CCA1224_SO-P8	SOPN-8	Tape & Reel	3.800 parts per reel



## **10 Revision History**

Revision	Date	Description
1.4	31-Oct-2019	Updated Template
1.3	24-Jul-2015	Updated Form
1.2	30-Apr-2015	Change of Part Number
1.1	25-Mar-2015	Changes in Timing and Bus
1.0	28-Aug-2014	Initial version

### 11 Disclaimer

Information in this document is believed to be accurate and reliable. However, Dialog Semiconductor does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information. Dialog Semiconductor furthermore takes no responsibility whatsoever for the content in this document if provided by any information source outside of Dialog Semiconductor.

Dialog Semiconductor reserves the right to change without notice the information published in this document, including without limitation the specification and the design of the related semiconductor products, software and applications.

Applications, software, and semiconductor products described in this document are for illustrative purposes only. Dialog Semiconductor makes no representation or warranty that such applications, software and semiconductor products will be suitable for the specified use without further testing or modification. Unless otherwise agreed in writing, such testing or modification is the sole responsibility of the customer and Dialog Semiconductor excludes all liability in this respect.

Customer notes that nothing in this document may be construed as a license for customer to use the Dialog Semiconductor products, software and applications referred to in this document. Such license must be separately sought by customer with Dialog Semiconductor.

All use of Dialog Semiconductor products, software and applications referred to in this document are subject to Dialog Semiconductor's Standard Terms and Conditions of Sale, available on the company website (www.dialog-semiconductor.com) unless otherwise stated.

Dialog and the Dialog logo are trademarks of Dialog Semiconductor plc or its subsidiaries. All other product or service names are the property of their respective owners.

© 2019 Dialog Semiconductor. All rights reserved.



### **Contents**

1
1 1
2
2
2
3
3
3
∠
∠
5
6
6
7
7
8
9
9
10
10
11
11
12

#### **IMPORTANT NOTICE AND DISCLAIMER**

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD-PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers who are designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only to develop an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third-party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising from your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Disclaimer Rev.1.01)

### **Corporate Headquarters**

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

#### **Trademarks**

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

#### **Contact Information**

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit <a href="https://www.renesas.com/contact-us/">www.renesas.com/contact-us/</a>.